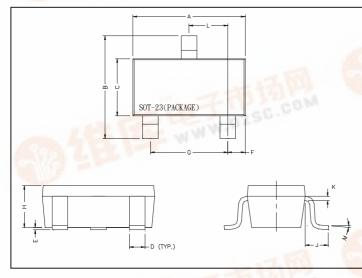
查询G491SD供应商

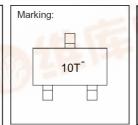
GTM ISSUED DATE :2003/01/28 REVISED DATE :2005/05/05B CORPORATION

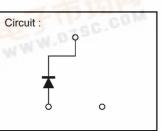
G491SD SURFACE MOUNT, SCHOTTKY BARRIER DIODE **VOLTAGE 25V, CURRENT 1A**

Description The G491SD is low power rectification for switching power supply.

Package Dimensions







REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	NEF.	Min.	Max.
Α	2.70	3.10	G	1.90 REF.	
В	2.40	2.80	Н	1.00	1.30
С	1.40	1.60	К	0.10	0.20
D	0.35	0.50	J	0.40	-
E	0	0.10	L	0.85	1.15
F	0.45	0.55	М	0°	10°

Absolute Maximum Ratings at Ta = 25°C

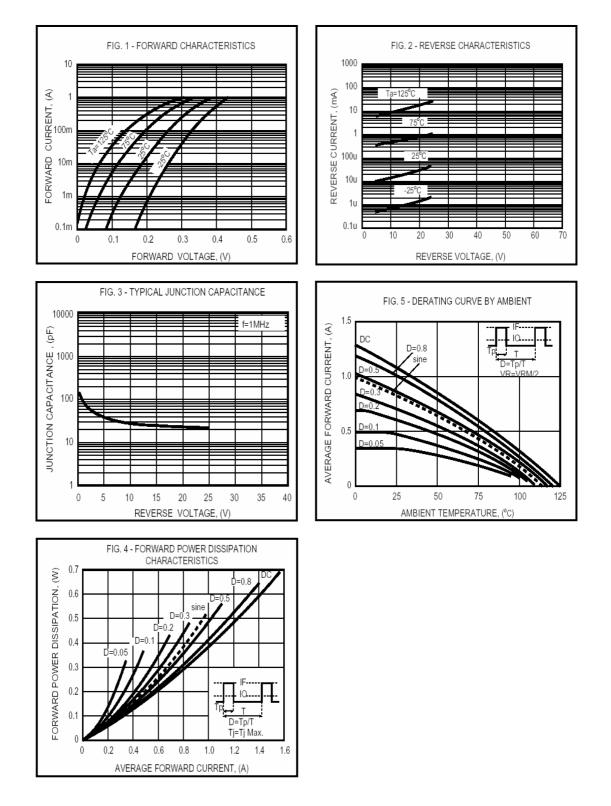
Parameter	Symbol	Ratings	Unit
Junction Temperature	Tj	+125	°C
Storage Temperature	Tstg	-40 ~ +125	°C
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	25	55CV-
Maximum RMS Voltage	V _{RMS}	18	V
Maximum DC Blocking Voltage	V _{DC}	20	V
Peak Forward Surge Current at 8.3mSec single half sine-wave	I _{FSM}	3	А
Typical Junction Capacitance between Terminal	CJ	30	pF
Maximum Average Forward Rectified Current	lo	1.0	А
Total Power Dissipation	PD	225	mW

Characteristics at $Ta = 25^{\circ}C$



ISSUED DATE :2003/01/28 REVISED DATE :2005/05/05B

Characteristics Curve



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